

### VS-GT400TH60N

RoHS

COMPLIANT

**Vishay Semiconductors** 

# Molding Type Module IGBT, 2-in-1 Package, 600 V and 400 A



Dual INT-A-PAK

PRIMARY CHARACTERISTICS						
V <sub>CES</sub>	600 V					
$I_C$ at $T_C$ = 80 °C	400 A					
V <sub>CE(on)</sub> (typical) at I <sub>C</sub> = 400 A, 25 °C	1.60 V					
Speed	8 kHz to 30 kHz					
Package	Dual INT-A-PAK					
Circuit configuration	Half bridge					

### FEATURES

- Low  $V_{CE(on)}$  trench IGBT technology
- Low switching losses
- 5 µs short circuit capability
- $V_{CE(on)}$  with positive temperature coefficient
- Maximum junction temperature 175 °C
- Low inductance case
- · Fast and soft reverse recovery antiparallel FWD
- Isolated copper baseplate using DCB (Direct Copper Bonding) technology
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **TYPICAL APPLICATIONS**

- UPS
- Switching mode power supplies
- Electronic welders

### DESCRIPTION

Vishay's IGBT power module provides ultralow conduction loss as well as short circuit ruggedness. It is designed for applications such as UPS and SMPS.

ABSOLUTE MAXIMUM RATINGS (T <sub>C</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Collector to emitter voltage	V <sub>CES</sub>		600	v	
Gate to emitter voltage	V <sub>GES</sub>		± 20	v	
Collector ourrent		T <sub>C</sub> = 25 °C	530		
Collector current I <sub>C</sub>		T <sub>C</sub> = 80 °C	400		
Pulsed collector current	I <sub>CM</sub> <sup>(1)</sup>	t <sub>p</sub> = 1 ms	800	А	
Diode continuous forward current	١ <sub>F</sub>		400		
Diode maximum forward current	I <sub>FM</sub>		800		
Maximum power dissipation	PD	T <sub>J</sub> = 175 °C	1600	W	
Short circuit withstand time	t <sub>SC</sub>	T <sub>J</sub> = 125 °C	5	μs	
l <sup>2</sup> t-value, diode	l <sup>2</sup> t	$V_{R} = 0 V, t = 10 ms, T_{J} = 125 \ ^{\circ}C$	10 900	A <sup>2</sup> s	
RMS isolation voltage	V <sub>ISOL</sub>	f = 50 Hz, t = 1 min	2500	V	

#### Note

<sup>(1)</sup> Repetitive rating: pulse width limited by maximum junction temperature

<b>IGBT ELECTRICAL SPECIFICATIONS</b> ( $T_c = 25$ °C unless otherwise noted)						
Collector to emitter breakdown voltage	V <sub>(BR)CES</sub>	$V_{GE} = 0 \text{ V}, \text{ I}_{C} = 2 \text{ mA}, \text{ T}_{J} = 25 ^{\circ}\text{C}$	600	-	-	
Collector to emitter saturation voltage	V <sub>CE(on)</sub>	$V_{GE}$ = 15 V, I <sub>C</sub> = 400 A, T <sub>J</sub> = 25 °C	-	1.6	2.05	V
		$V_{GE}$ = 15 V, I <sub>C</sub> = 400 A, T <sub>J</sub> = 175 °C	-	2.0	-	
Gate to emitter threshold voltage	V <sub>GE(th)</sub>	$V_{CE} = V_{GE}$ , $I_C = 4$ mA, $T_J = 25$ °C	4.0	-	6.5	
Zero gate voltage collector current	I <sub>CES</sub>	$V_{CE} = V_{CES}, V_{GE} = 0 \text{ V}, \text{ T}_{J} = 25 ^{\circ}\text{C}$	-	-	5.0	mA
Gate to emitter leakage current	I <sub>GES</sub>	$V_{GE} = V_{GES}, V_{CE} = 0 \text{ V}, \text{ T}_{J} = 25 ^{\circ}\text{C}$	-	-	400	nA

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SWITCHING CHARACTERISTICS	S					
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Turn-on delay time	t <sub>d(on)</sub>		-	35	-	
Rise time	t <sub>r</sub>		-	70	-	-
Turn-off delay time	t <sub>d(off)</sub>	$V_{CC}$ = 400 V, I <sub>C</sub> = 400 A, R <sub>g</sub> = 1.3 Ω,	-	180	-	ns
Fall time	t <sub>f</sub>	$V_{GE} = \pm 15 \text{ V}, T_{J} = 25 \text{ °C}$	-	75	-	
Turn-on switching loss	E <sub>on</sub>		-	14.1	-	
Turn-off switching loss	E <sub>off</sub>	-	-	10.0	-	- mJ
Turn-on delay time	t <sub>d(on)</sub>		-	37	-	
Rise time	t <sub>r</sub>		-	72	-	- ns
Turn-off delay time	t <sub>d(off)</sub>	$V_{CC}$ = 400 V, $I_C$ = 400 A, $R_g$ = 1.3 Ω,	-	220	-	
Fall time	t <sub>f</sub>	V <sub>GE</sub> = ± 15 V, T <sub>J</sub> = 175 °C	-	84	-	
Turn-on switching loss	E <sub>on</sub>		-	23.2	-	
Turn-off switching loss	E <sub>off</sub>		-	16.8	-	mJ
Input capacitance	Cies		-	30.8	-	
Output capacitance	C <sub>oes</sub>	V <sub>GE</sub> = 0 V, V <sub>CE</sub> = 30 V, f = 1.0 MHz	-	2.12	-	nF
Reverse transfer capacitance	C <sub>res</sub>		-	0.92	-	
SC data	I <sub>SC</sub>	$\begin{array}{l} t_{sc} \leq 5 \; \mu s,  V_{GE} = 15 \; V,  T_J = 125 \; ^{\circ}C, \\ V_{CC} = 360 \; V,  V_{CEM} \leq 600 \; V \end{array}$	-	TBD	-	А
Internal gate resistance	R <sub>gint</sub>		-	1.3	-	Ω
Stray inductance	L <sub>CE</sub>		-	-	20	nH
Module lead resistance, terminal to chip	R <sub>CC'+EE'</sub>	T <sub>C</sub> = 25 °C	-	0.35	-	mΩ

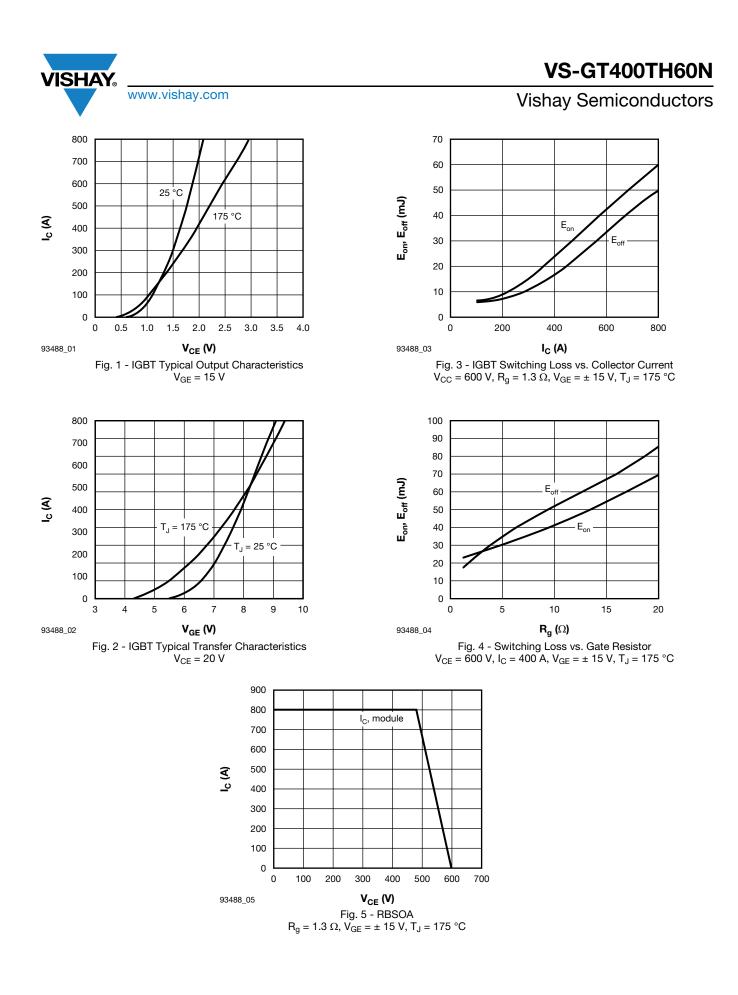
<b>DIODE ELECTRICAL SPECIFICATIONS</b> ( $T_C = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	SYMBOL	TEST CONDIT	TEST CONDITIONS MIN. TYP. M			MAX.	UNITS
Diode forward voltage	V	I <sub>F</sub> = 400 A	T <sub>J</sub> = 25 °C	-	1.38	1.80	- V
Didde forward voltage	V <sub>F</sub>	I <sub>F</sub> = 400 A	T <sub>J</sub> = 125 °C	-	1.41	-	
Diada rayarga ragayany abarga	0	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C	-	15.5	-	
Diode reverse recovery charge	Q <sub>rr</sub>		T <sub>J</sub> = 125 °C	-	28.5	-	μC
Diada paale rayaraa raaayar eyeraat		$I_F = 400 \text{ A}, V_R = 300 \text{ V},$ dI/dt = -7000 A/µs,	T <sub>J</sub> = 25 °C	-	265	-	^
Diode peak reverse recovery current	Irr	$V_{GF} = -15 V$	T <sub>J</sub> = 125 °C	-	335	-	A
	E	E <sub>rec</sub>	T <sub>J</sub> = 25 °C	-	3.5	-	ml
Diode reverse recovery energy	⊏rec		T <sub>J</sub> = 125 °C	-	7.5	-	mJ

THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Operating junction temperatur	re range	TJ		-	-	175	°C
Storage temperature range		T <sub>Stg</sub>		-40	-	125	
Junction to case	IGBT	Р		-	-	0.094	
per ½ module	Diode	R <sub>thJC</sub>		-	-	0.158	K/W
Case to sink		R <sub>thCS</sub>	Conductive grease applied	-	0.035	-	
Mounting torque			Power terminal screw: M6		2.5 to 5.0		Nm
Mounting torque			Mounting screw: M6		3.0 to 5.0		
Weight					300		g

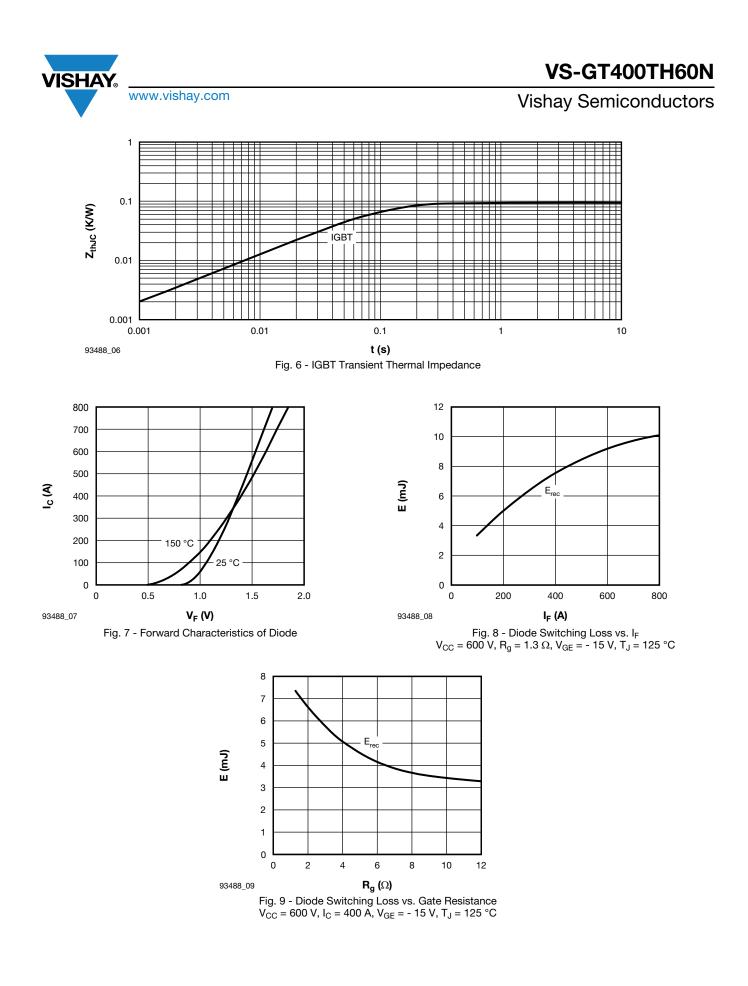
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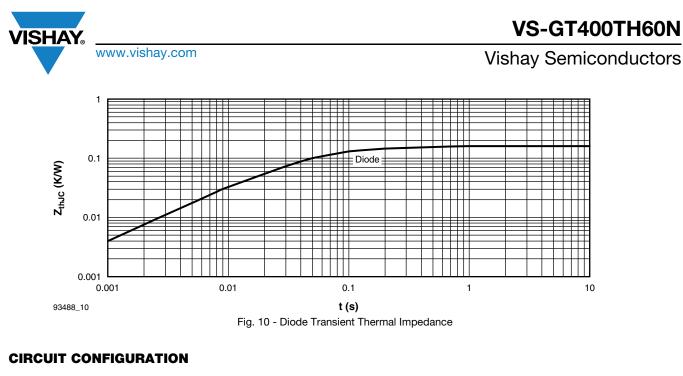
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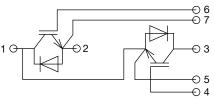


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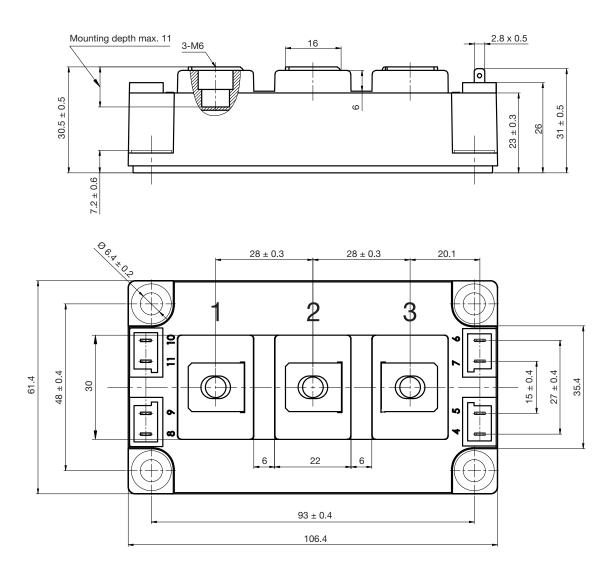


## **Outline Dimensions**

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## Double INT-A-PAK

**DIMENSIONS** in millimeters (inches)



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